

FEATURES

Set of 4 narrow-band VCOs with consistent sensitivity vs. frequency

RF and tuning ports common to all 4 VCOs

RF output operates from fundamental oscillators with no subharmonic oscillations

Up to 8 dBm RF output power

Power mute capability

No external resonator required

40-lead, 6 mm × 6 mm LFCSP

APPLICATIONS

Electronic test and measurement

Industrial and medical instrumentation

Point to point and multipoint radios

Aerospace and defense

Wireless communication infrastructure

FUNCTIONAL BLOCK DIAGRAM

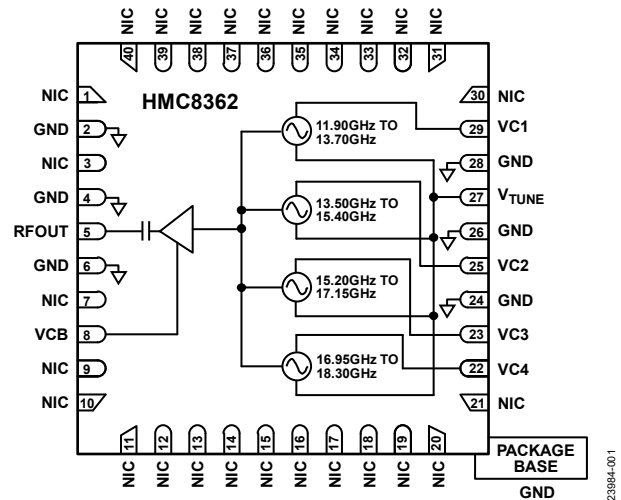


Figure 1.

GENERAL DESCRIPTION

The HMC8362 is a gallium arsenide (GaAs), quadband, monolithic microwave integrated circuit (MMIC), voltage controlled oscillator (VCO) designed to offer wideband capabilities without compromising on phase noise performance. The device integrates four independent, narrow-band VCOs with overlapping frequency bands, operating at a fundamental frequency range of 11.90 GHz to 18.30 GHz. The consistent tuning sensitivity across all frequency bands simplifies the synthesizer loop filter design.

The tuning port is common to all VCO cores for a simpler design of the phase-locked loop (PLL) feedback path. The HMC8362 also offers a low typical current consumption of 72 mA for power sensitive applications.

The HMC8362 integrates resonators, negative resistance devices, and varactor diodes. The monolithic structure of the oscillator offers very low phase noise, optimal temperature stability, and is immune to vibration and process variation.

The four VCOs are packaged in a single, 6 mm × 6 mm, surface-mount lead frame chip scale package (LFCSP), and require no external matching components.

Combined with a high frequency, high performance phase-locked loop (PLL), the ADF41513, the HMC8362 offers a complete RF or microwave frequency generation solution.

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REVISION HISTORY

9/2020—Revision A: Initial Version

SPECIFICATIONS

$T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, Band 1 to Band 4 supply voltage (V_{CC}) = 5 V, buffer supply voltage (V_{CB}) = 5 V, unless otherwise noted.

Table 1.

| Parameter | Min | Typ | Max | Unit | Test Conditions/Comments |
|---------------------------------------|-------|------|-------|-------------------------|---|
| RF OUTPUT CHARACTERISTICS | | | | | |
| Frequency (f_{OUT}) | | | | | |
| Band 1 | 11.90 | | 13.70 | GHz | |
| Band 2 | 13.50 | | 15.40 | GHz | |
| Band 3 | 15.20 | | 17.15 | GHz | |
| Band 4 | 16.95 | | 18.30 | GHz | |
| Output Power (P_{OUT}) | | | | | |
| Band 1 | -4 | +1.9 | +8 | dBm | |
| Band 2 | -4 | +0.8 | +8 | dBm | |
| Band 3 | -4 | +3 | +8 | dBm | |
| Band 4 | -4 | +1.8 | +8 | dBm | |
| P_{OUT} with Buffer Amplifier Muted | | | | | Measured at $V_{CB} = 0\text{ V}$ |
| Band 1 | | -27 | | dBm | |
| Band 2 | | -20 | | dBm | |
| Band 3 | | -25 | | dBm | |
| Band 4 | | -30 | | dBm | |
| Tuning Sensitivity | | | | | |
| Band 1 | | 226 | | MHz/V | |
| Band 2 | | 246 | | MHz/V | |
| Band 3 | | 272 | | MHz/V | |
| Band 4 | | 291 | | MHz/V | |
| Frequency Drift Rate | | | | | Drift specifications are not de-embedded to remove contribution from the evaluation board |
| Band 1 | | 1.7 | | MHz/ $^{\circ}\text{C}$ | |
| Band 2 | | 2 | | MHz/ $^{\circ}\text{C}$ | |
| Band 3 | | 2.4 | | MHz/ $^{\circ}\text{C}$ | |
| Band 4 | | 2.6 | | MHz/ $^{\circ}\text{C}$ | |
| Harmonic Content | | | | | Worst measured value at typical |
| Second Harmonic | | 12 | | dBc | |
| Third Harmonic | | 30 | | dBc | |
| Frequency Pulling | | 0.5 | | MHz p-p | Worst measured value at typical |
| Frequency Pushing | | 30 | | MHz/V | Worst measured value at typical |
| Output Return Loss | | 8 | | dB | Worst measured value at typical |
| POWER SUPPLIES | | | | | |
| Supply Voltage | 4.75 | 5.0 | 5.25 | V | |
| Supply Current (I_{CC}) | | | | | |
| Band 1 | | 63 | | mA | |
| Band 2 | | 63 | | mA | |
| Band 3 | | 67 | | mA | |
| Band 4 | | 67 | | mA | |
| Buffer Amplifier | | 9 | | mA | |
| Total Supply Current | | 72 | 95 | mA | Total supply current is for the output buffer and one VCO band; only one VCO band must be powered at a time |
| Tuning Voltage | 1.0 | | 13.5 | V | |
| Tuning Port Leakage Current | | | 60 | μA | $V_{TUNE} = 13.5\text{ V}$, where the maximum tune port leakage current is measured |

| Parameter | Min | Typ | Max | Unit | Test Conditions/Comments |
|-----------------------------|-----|------|-----|--------|--------------------------|
| SINGLE SIDEBAND PHASE NOISE | | | | | |
| Band 1 | | | | | |
| 10 kHz | | -74 | | dBc/Hz | |
| 100 kHz | | -101 | | dBc/Hz | |
| 1 MHz | | -128 | | dBc/Hz | |
| Band 2 | | | | | |
| 10 kHz | | -71 | | dBc/Hz | |
| 100 kHz | | -99 | | dBc/Hz | |
| 1 MHz | | -126 | | dBc/Hz | |
| Band 3 | | | | | |
| 10 kHz | | -69 | | dBc/Hz | |
| 100 kHz | | -96 | | dBc/Hz | |
| 1 MHz | | -124 | | dBc/Hz | |
| Band 4 | | | | | |
| 10 kHz | | -66 | | dBc/Hz | |
| 100 kHz | | -94 | | dBc/Hz | |
| 1 MHz | | -122 | | dBc/Hz | |

ABSOLUTE MAXIMUM RATINGS

Table 2.

| Parameter | Rating |
|--|-----------------|
| V_{C1} to V_{C4} , V_{CB} ¹ | 5.5 V dc |
| V_{TUNE} | 0 V to 15 V |
| Temperature | |
| Operating | –40°C to +85°C |
| Storage | –65°C to +150°C |
| Maximum Junction to Maintain 1 Million Hours Mean Time to Failure (MTTF) | 135°C |
| Peak Reflow (Moisture Sensitivity Level (MSL) 3 Rating) | 260°C |

¹ Only one VCO band must be powered at a time. V_{C1} to V_{C4} are the Band 1 to Band 4 supply voltages on the VC1 to VC4 pins, respectively.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

θ_{JA} is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure. θ_{JC} is the junction to case thermal resistance.

Table 3. Thermal Resistance

| Package Type ¹ | θ_{JA} | θ_{JC} | Unit |
|---------------------------|---------------|---------------|------|
| HCP-40-1 | 27.50 | 17.96 | °C/W |

¹ The thermal impedance simulated values are based on the JE5D51 standard using 2S2P on FR4 with four standard JEDEC vias (0.3 mm diameter, 0.025 mm plating, and 1.2 mm pitch).

ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

Human body model (HBM) per JEDEC JS-001.

Charged device model (CDM) per ANSI/ESDA/JEDEC JS-002.

ESD Ratings for HMC8362

Table 4. HMC8362, 40-Lead LFCSP

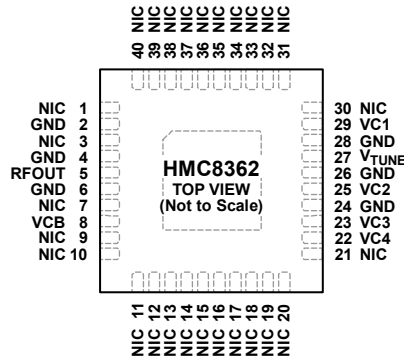
| ESD Model | Withstand Threshold (V) | Class |
|-----------|-------------------------|-------|
| HBM | ±500 | 1A |
| CDM | ±1000 | C3 |

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



- NOTES**
1. NOT INTERNALLY CONNECTED. HOWEVER, THESE PINS CAN BE CONNECTED TO RF OR DC GROUND WITHOUT AFFECTING THE PERFORMANCE OF THE DEVICE.
 2. EXPOSED PAD. THE PACKAGE BOTTOM HAS AN EXPOSED METAL PAD THAT MUST BE CONNECTED TO RF OR DC GROUND.

23984-002

Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|----------------------------|----------|--|
| 1, 3, 7, 9 to 21, 30 to 40 | NIC | Not Internally Connected. However, these pins can be connected to RF or dc ground without affecting the performance of the device. |
| 2, 4, 6, 24, 26, 28 | GND | Ground. The GND pins must be connected to RF or dc ground. |
| 5 | RFOUT | RF Output. The RFOUT pin is ac-coupled, and maintaining a voltage standing wave ratio (VSWR) load of $\leq 2.0:1$ across frequency is recommended. |
| 8 | VCB | Buffer Supply Voltage. |
| 22 | VC4 | Band 4 Supply Voltage. |
| 23 | VC3 | Band 3 Supply Voltage. |
| 25 | VC2 | Band 2 Supply Voltage. |
| 27 | VTUNE | Control Voltage and Modulation Input. The modulation bandwidth is dependent on the drive source impedance. |
| 29 | VC1 | Band 1 Supply Voltage. |
| | EP | Exposed Pad. The package bottom has an exposed metal pad that must be connected to RF or dc ground. |

INTERFACE SCHEMATICS

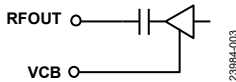


Figure 3. RFOUT and VCB Interface Schematic

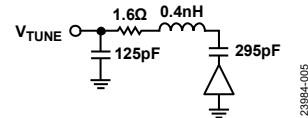


Figure 5. VTUNE Interface Schematic

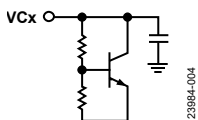


Figure 4. VC1 to VC4 Interface Schematic



Figure 6. GND Interface Schematic

TYPICAL PERFORMANCE CHARACTERISTICS

BAND 1: 11.90 GHz TO 13.70 GHz, $V_{CC} = 5 V$

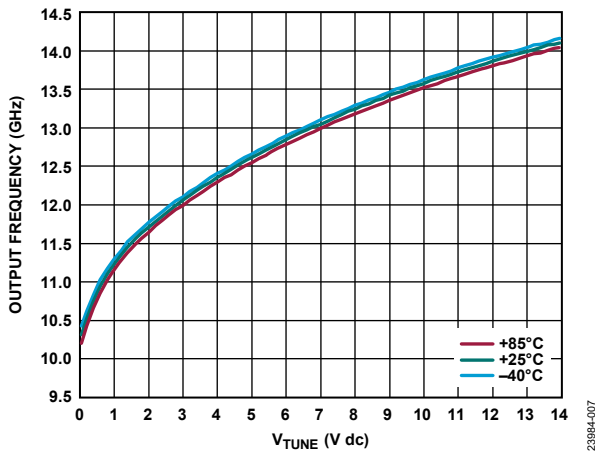


Figure 7. Output Frequency vs. V_{TUNE} for Various Temperatures

23984-007

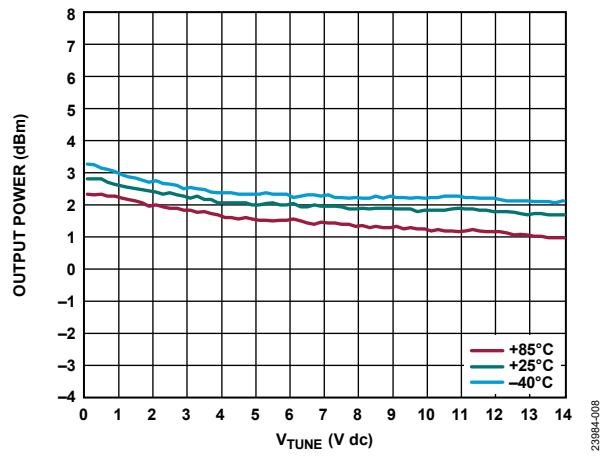


Figure 10. Output Power vs. V_{TUNE} for Various Temperatures

23984-008

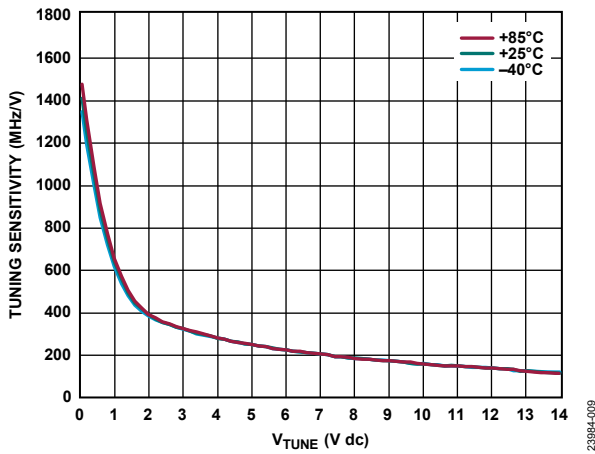


Figure 8. Tuning Sensitivity vs. V_{TUNE} for Various Temperatures

23984-009

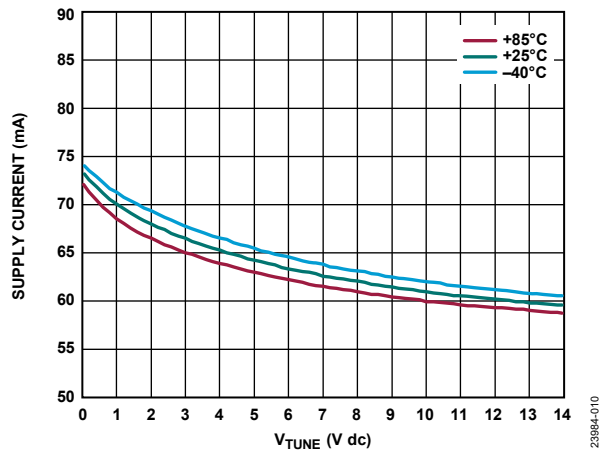


Figure 11. Supply Current vs. V_{TUNE} for Various Temperatures

23984-010

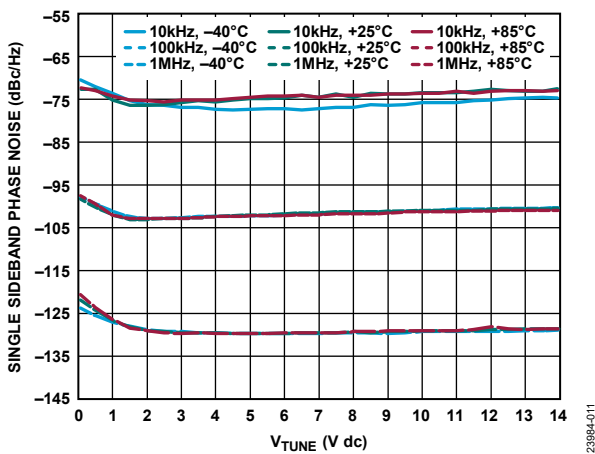


Figure 9. Single Sideband Phase Noise vs. V_{TUNE} for Various Temperatures and Frequencies

23984-011

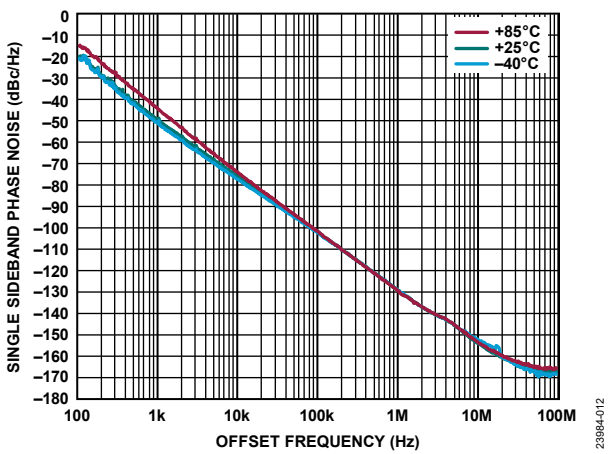


Figure 12. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at $V_{TUNE} = 5 V$

23984-012

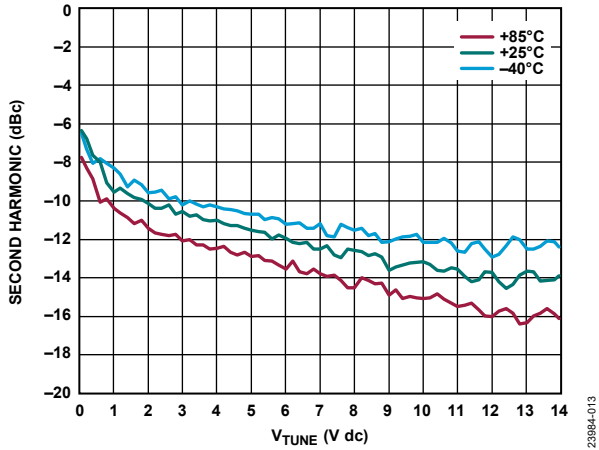


Figure 13. Second Harmonic vs. V_{TUNE} for Various Temperatures

23984-013

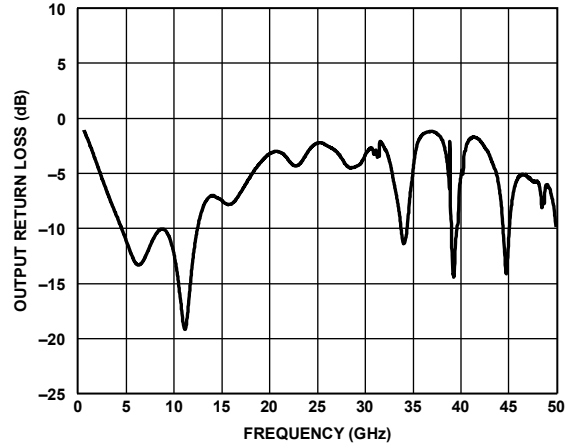


Figure 15. Output Return Loss vs. Frequency at $V_{TUNE} = 7.25$ V, $V_{CB} = 5$ V, $T_A = 25^\circ\text{C}$

23984-115

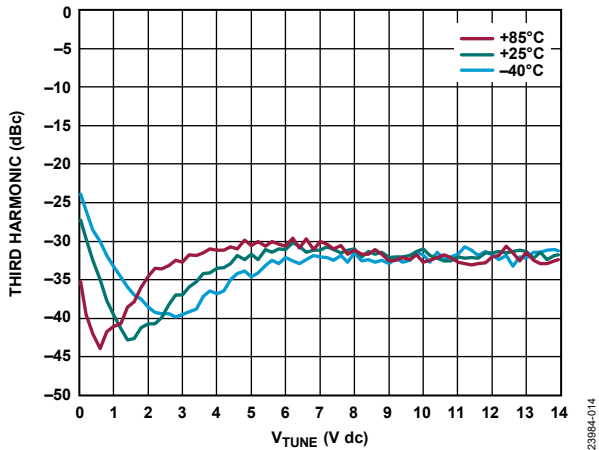


Figure 14. Third Harmonic vs. V_{TUNE} for Various Temperatures

23984-014

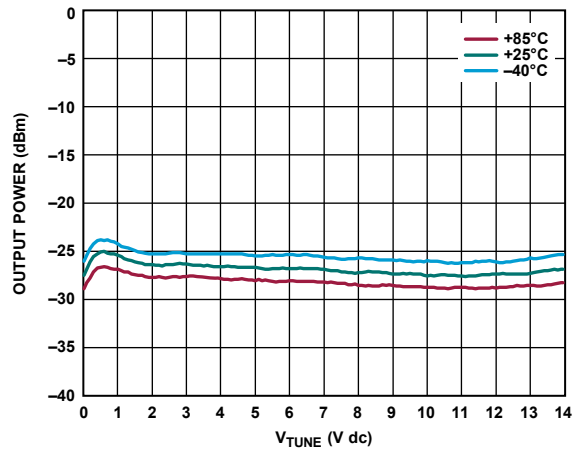


Figure 16. Output Power vs. V_{TUNE} at $V_{CB} = 0$ V for Various Temperatures

23984-016

BAND 2: 13.50 GHz TO 15.40 GHz, $V_{CC} = 5 V$

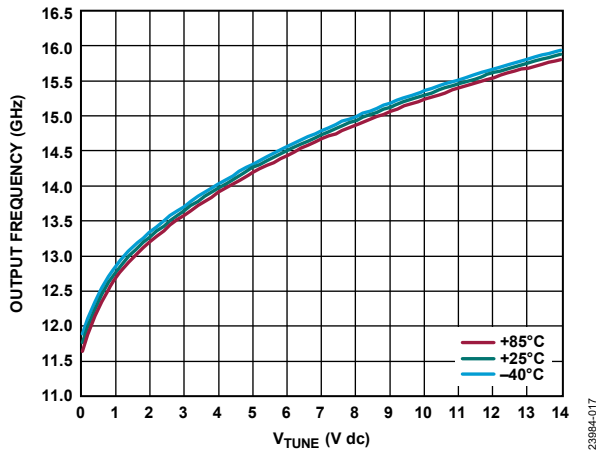


Figure 17. Output Frequency vs. V_{TUNE} for Various Temperatures

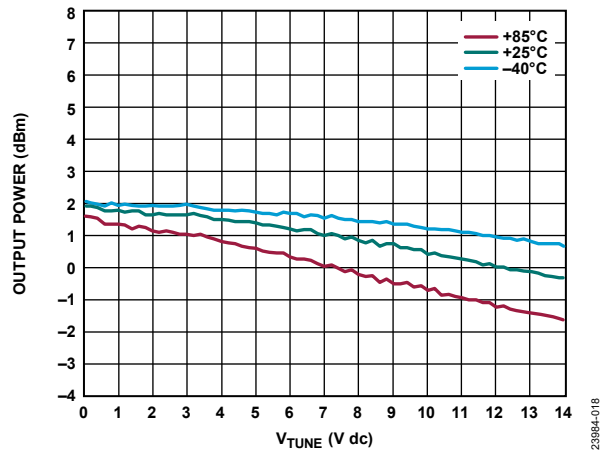


Figure 20. Output Power vs. V_{TUNE} for Various Temperatures

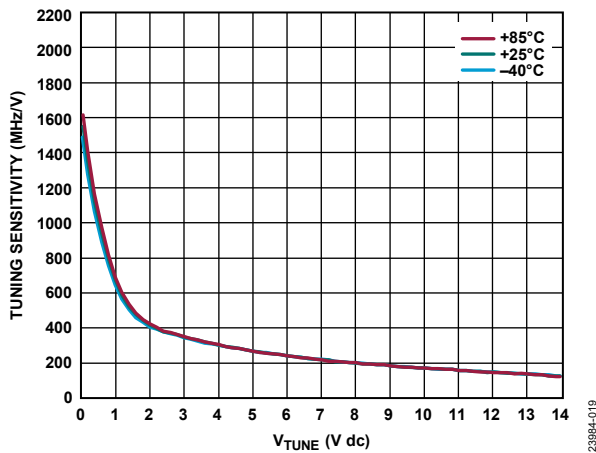


Figure 18. Tuning Sensitivity vs. V_{TUNE} for Various Temperatures

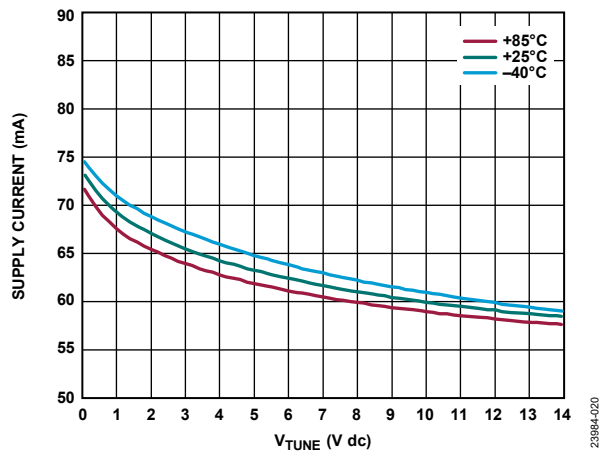


Figure 21. Supply Current vs. V_{TUNE} for Various Temperatures

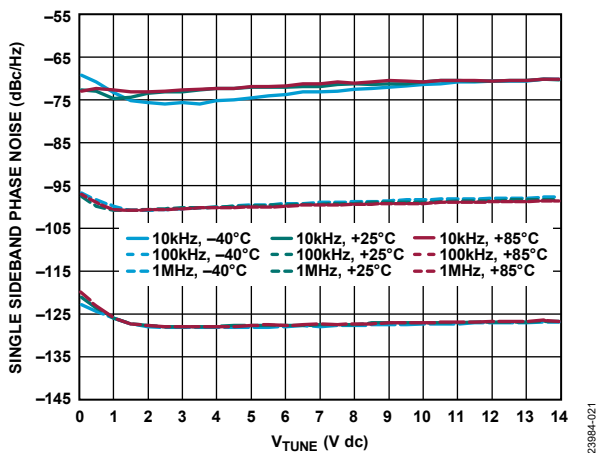


Figure 19. Single Sideband Phase Noise vs. V_{TUNE} for Various Temperatures and Frequencies

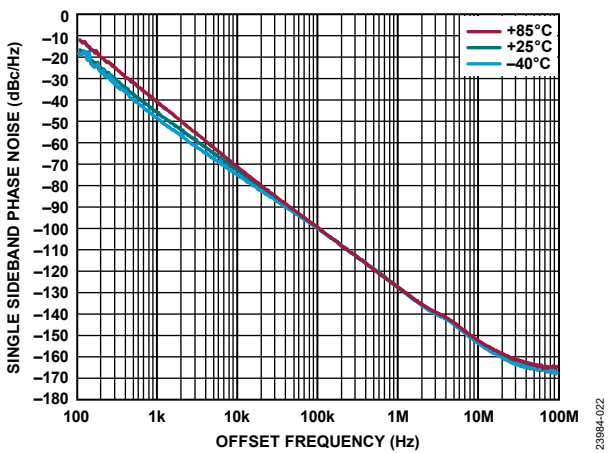


Figure 22. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at $V_{TUNE} = 5 V$

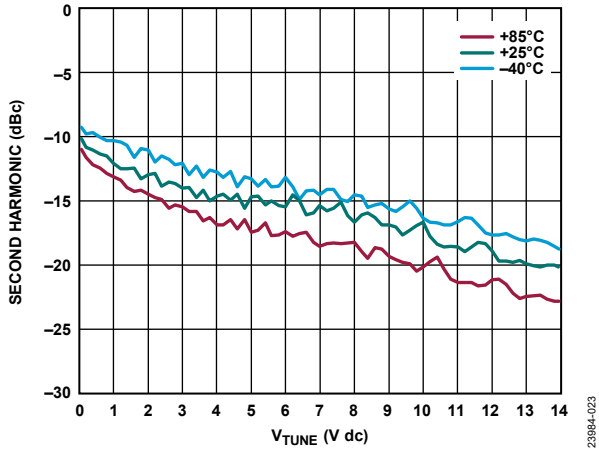


Figure 23. Second Harmonic vs. V_{TUNE} for Various Temperatures

23984-023

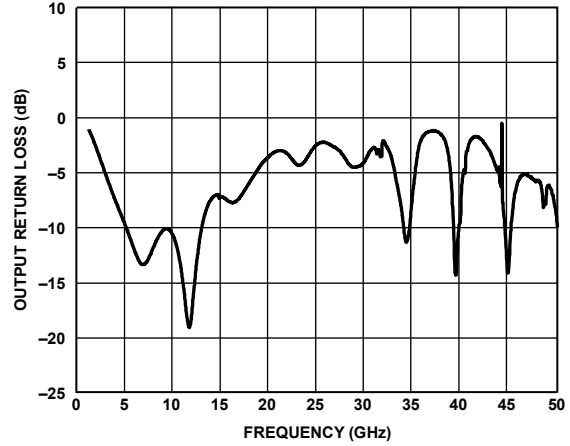


Figure 25. Output Return Loss vs. Frequency at $V_{TUNE} = 7.25$ V, $V_{CB} = 5$ V, $T_A = 25^\circ\text{C}$

23984-125

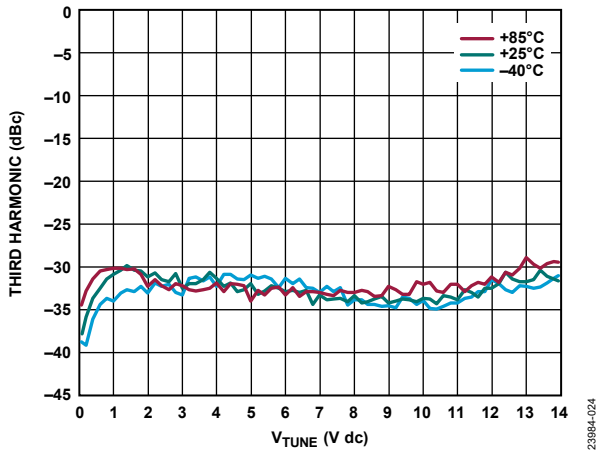


Figure 24. Third Harmonic vs. V_{TUNE} for Various Temperatures

23984-024

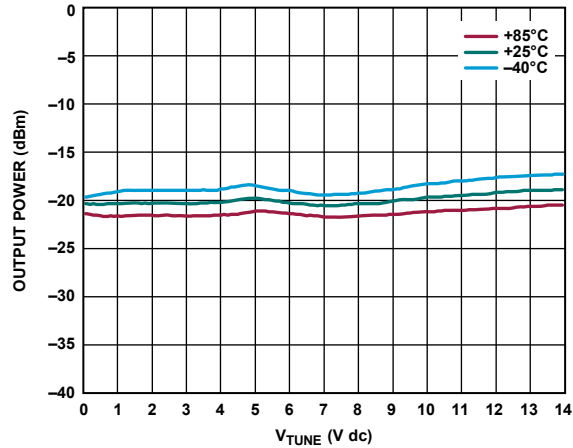


Figure 26. Output Power vs. V_{TUNE} at $V_{CB} = 0$ V for Various Temperatures

23984-026

BAND 3: 15.20 GHz TO 17.15 GHz, $V_{CC} = 5 V$

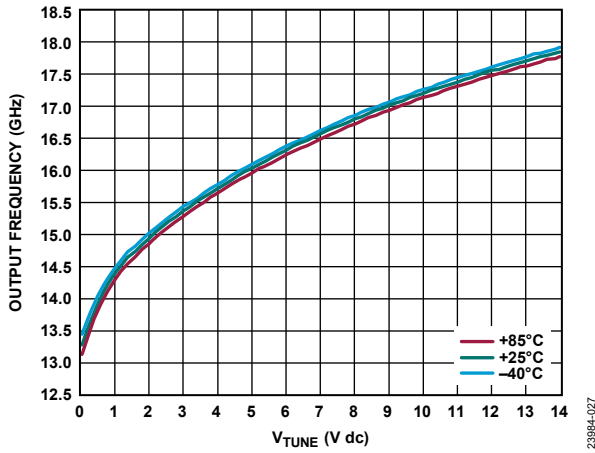


Figure 27. Output Frequency vs. V_{TUNE} for Various Temperatures

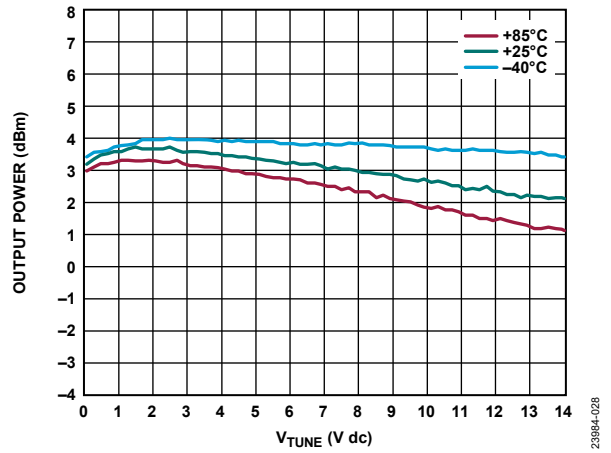


Figure 30. Output Power vs. V_{TUNE} for Various Temperatures

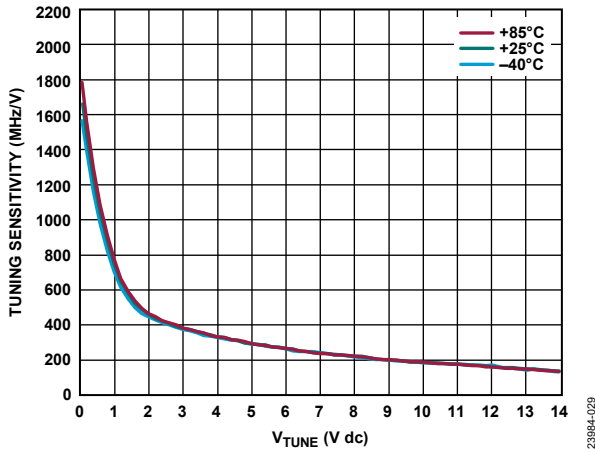


Figure 28. Tuning Sensitivity vs. V_{TUNE} for Various Temperatures

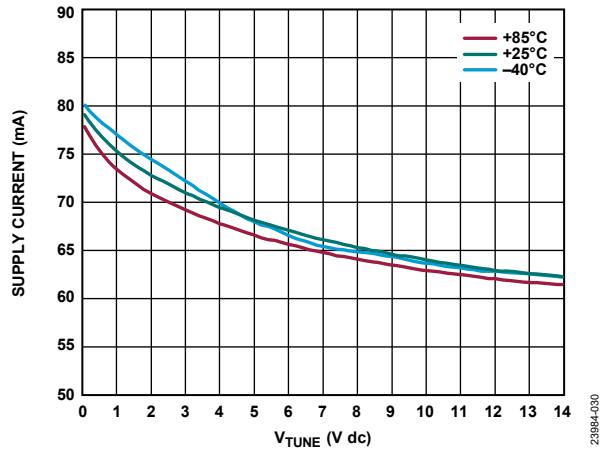


Figure 31. Supply Current vs. V_{TUNE} for Various Temperatures

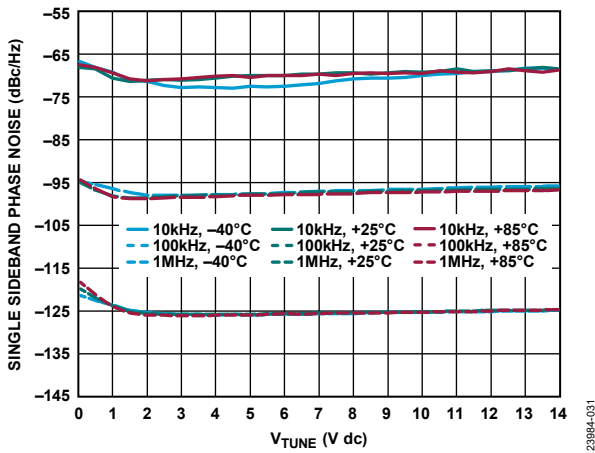


Figure 29. Single Sideband Phase Noise vs. V_{TUNE} for Various Temperatures and Frequencies

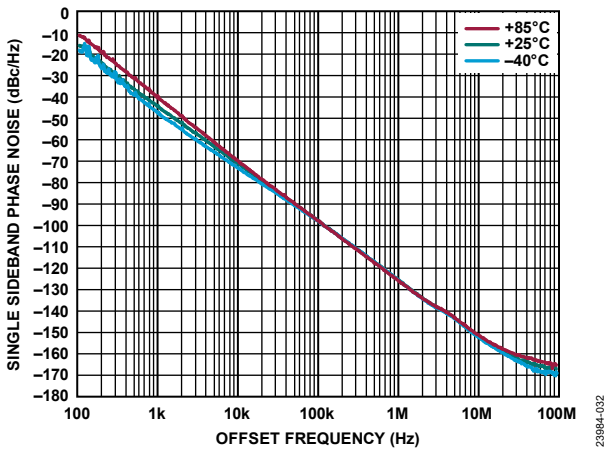


Figure 32. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at $V_{TUNE} = 5 V$

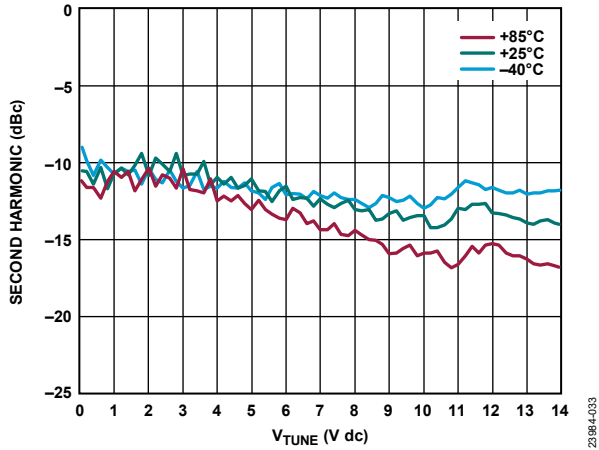


Figure 33. Second Harmonic vs. V_{TUNE} for Various Temperatures

23984-033

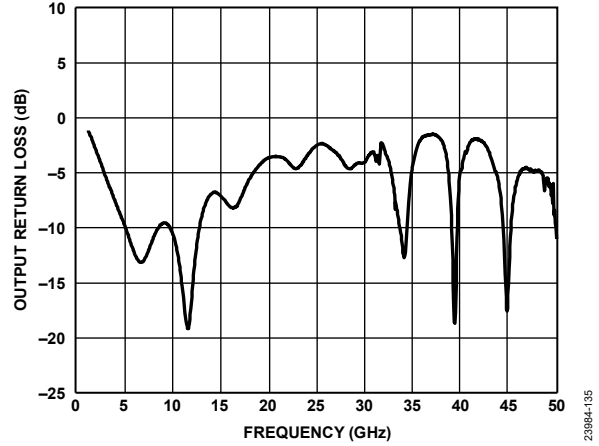


Figure 35. Output Return Loss vs. Frequency at $V_{TUNE} = 7.25\text{ V}$, $V_{CC} = 5\text{ V}$, $V_{CB} = 5\text{ V}$, $T = 25^\circ\text{C}$

23984-135

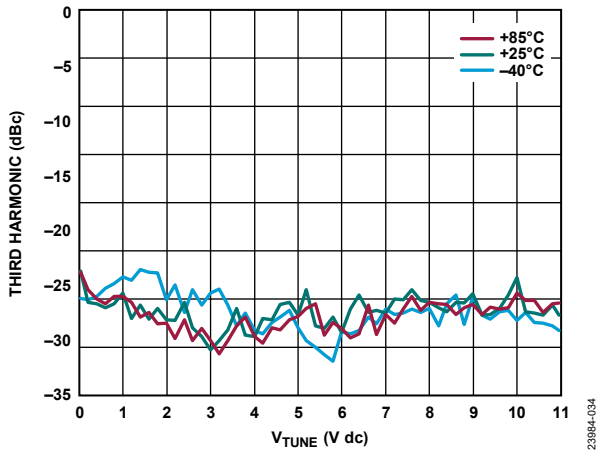


Figure 34. Third Harmonic vs. V_{TUNE} for Various Temperatures, (Measurement Up to 6.5 V Only Due to Equipment Limitation)

23984-034

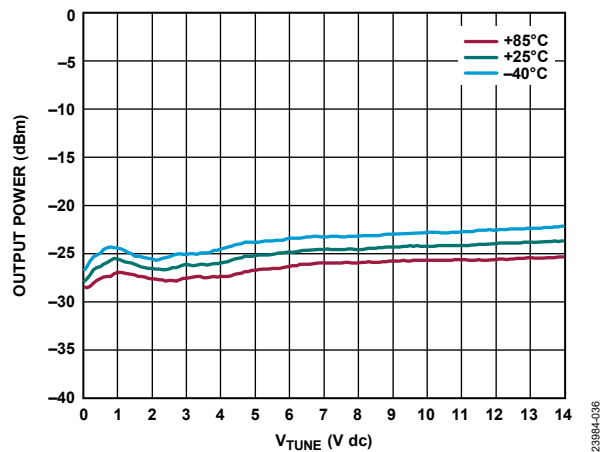


Figure 36. Output Power vs. V_{TUNE} at $V_{CB} = 0\text{ V}$ for Various Temperatures

23984-036

BAND 4: 16.95 GHz TO 18.30 GHz, $V_{CC} = 5 V$

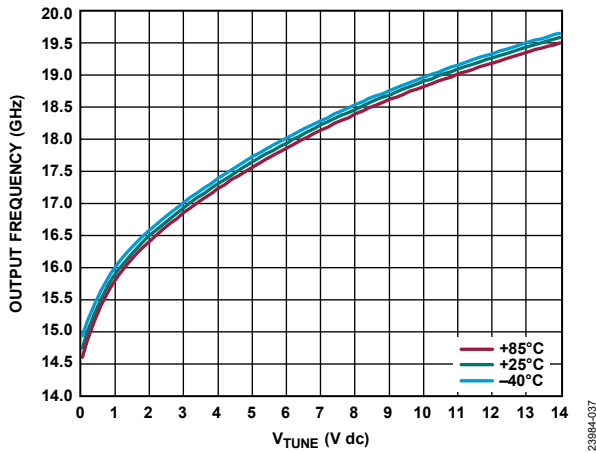


Figure 37. Output Frequency vs. V_{TUNE} for Various Temperatures

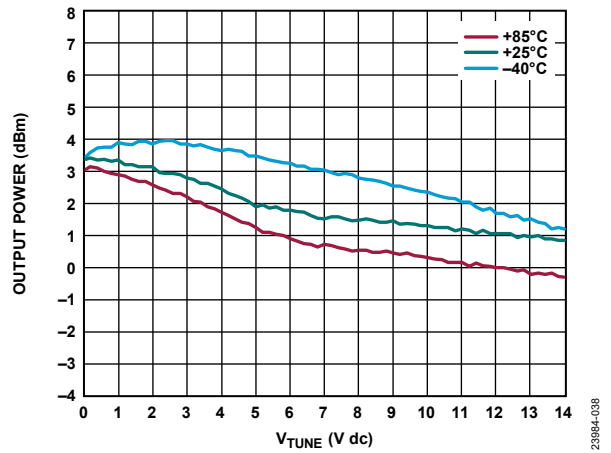


Figure 40. Output Power vs. V_{TUNE} for Various Temperatures

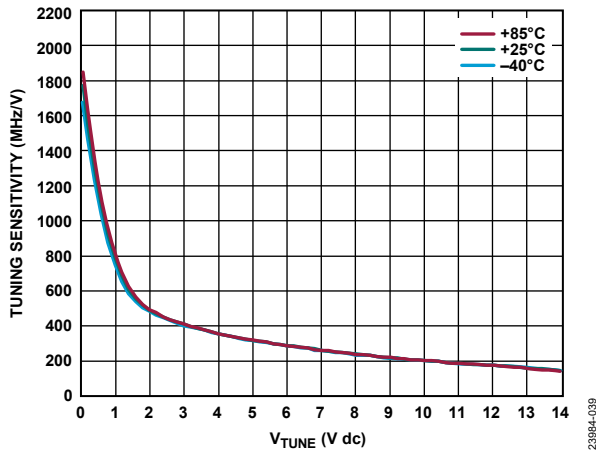


Figure 38. Tuning Sensitivity vs. V_{TUNE} for Various Temperatures

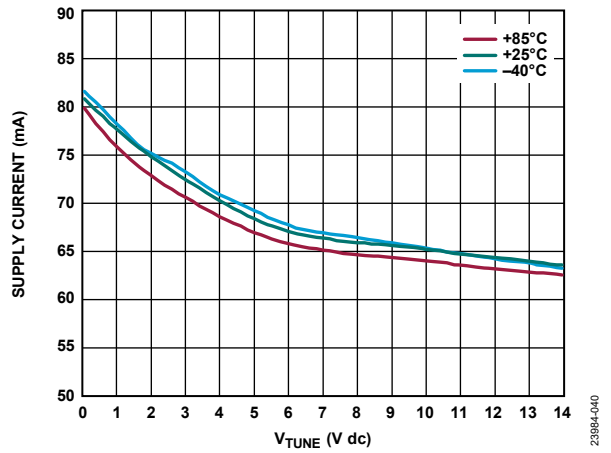


Figure 41. Supply Current vs. V_{TUNE} for Various Temperatures

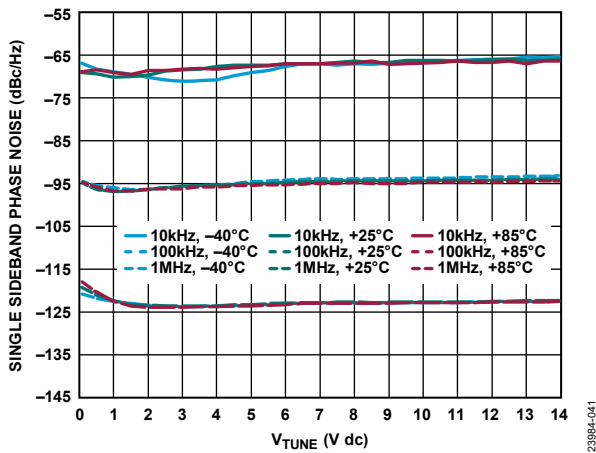


Figure 39. Single Sideband Phase Noise vs. V_{TUNE} for Various Temperatures and Frequencies

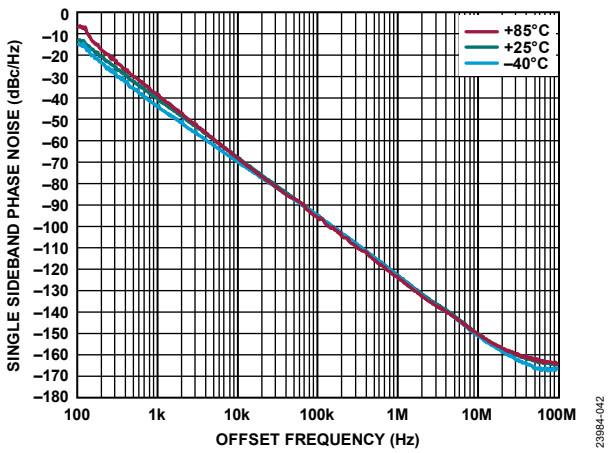


Figure 42. Single Sideband Phase Noise vs. Offset Frequency for Various Temperatures at $V_{TUNE} = 5 V$

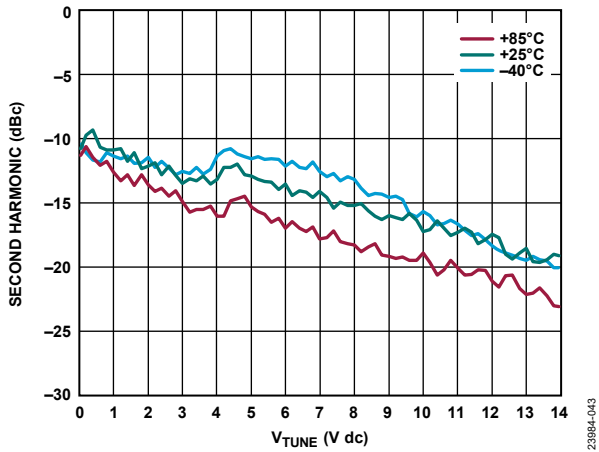


Figure 43. Second Harmonic vs. V_{TUNE} for Various Temperatures

23984-043

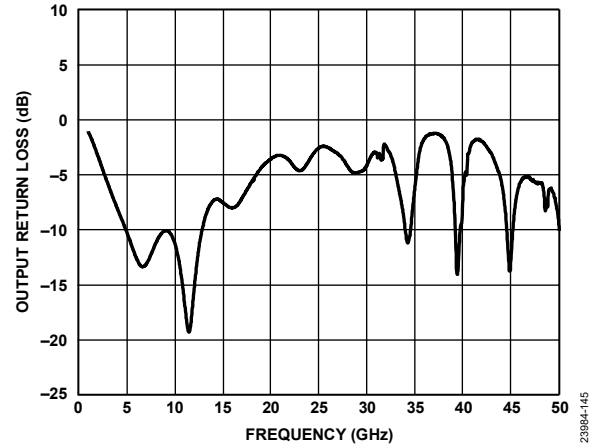


Figure 45. Output Return Loss vs. Frequency at $V_{TUNE} = 7.25$ V, $V_{CB} = 5$ V, $T_A = 25^\circ\text{C}$

23984-145

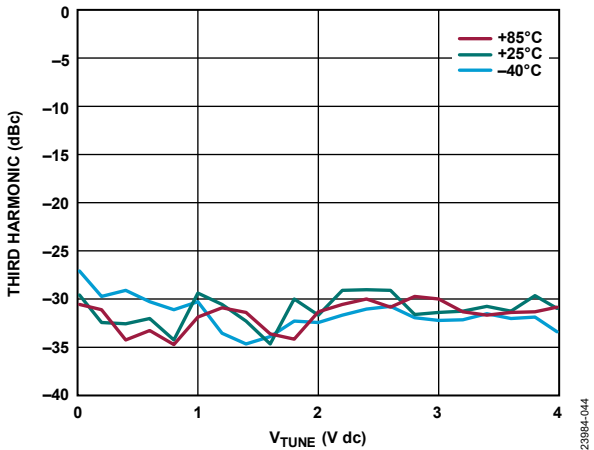


Figure 44. Third Harmonic vs. V_{TUNE} for Various Temperatures (Measurement Up to 6.5 V Only Due to Equipment Limitation)

23984-044

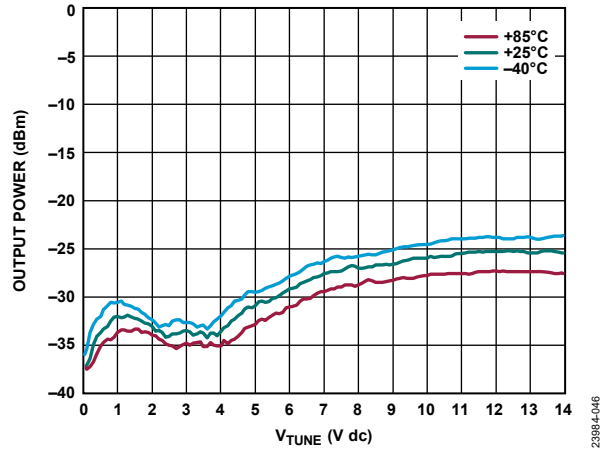


Figure 46. Output Power vs. V_{TUNE} at $V_{CB} = 0$ V for Various Temperatures

23984-046

THEORY OF OPERATION

The HMC8362 consists of four fundamental VCOs with overlapping frequency ranges to ensure continuous frequency coverage from 11.90 GHz to 18.30 GHz over all conditions.

Using four oscillators instead of a single oscillator to span the frequency range reduces the percent bandwidth and tuning sensitivity of each oscillator, improving phase noise performance.

Tuning sensitivity flatness across the frequency range is also improved and simplifies the loop filter design in synthesizer applications. The tuning sensitivity is similar across the four VCO cores, which means that the loop bandwidth and phase margin of the loop filter vary less overall vs. a single oscillator solution.

The four oscillators share a common tune port, which means that even though the active devices in the unused VCO cores are not being biased, the resonant tanks of all four VCO cores

are in parallel and being tuned simultaneously. A single buffer amplifier is also shared by all four VCOs.

The upper circuitry of the buffer amplifier is biased by VCB (Pin 8). The lower portion of the buffer amplifier or VCB remains off and very little current flows until one of the VCO cores is enabled.

The lower circuitry of the buffer amplifier is enabled when the RF signal of any one of the four VCOs arrives at its input. If VCB is biased and any VCO core is enabled, current flows through the buffer amplifier and the RF signal propagates to RFOUT (Pin 5).

The buffer amplifier is designed to support only one VCO at a time. Avoid enabling more than one oscillator at a time because multiple oscillators stress the buffer amplifier enough to reduce its long-term operating life.

APPLICATIONS INFORMATION

The HMC8362 serves as the local oscillator (LO) in microwave synthesizer applications. The primary applications for this device are point to point and multipoint radios, military radars, test and measurement, industrial and medical equipment, and wireless communication infrastructure. The low phase noise allows higher orders of modulation and offers improved bit error rates in communication systems. Stable loop filter design is easily achieved due to the linear, monotonic tuning sensitivity across the four-VCO core, and higher output power minimizes the gain required to drive subsequent stages. The cascode output buffer amplifier stage guarantees stability over a wide range of output load conditions and improves the pulling performance of the VCO cores.

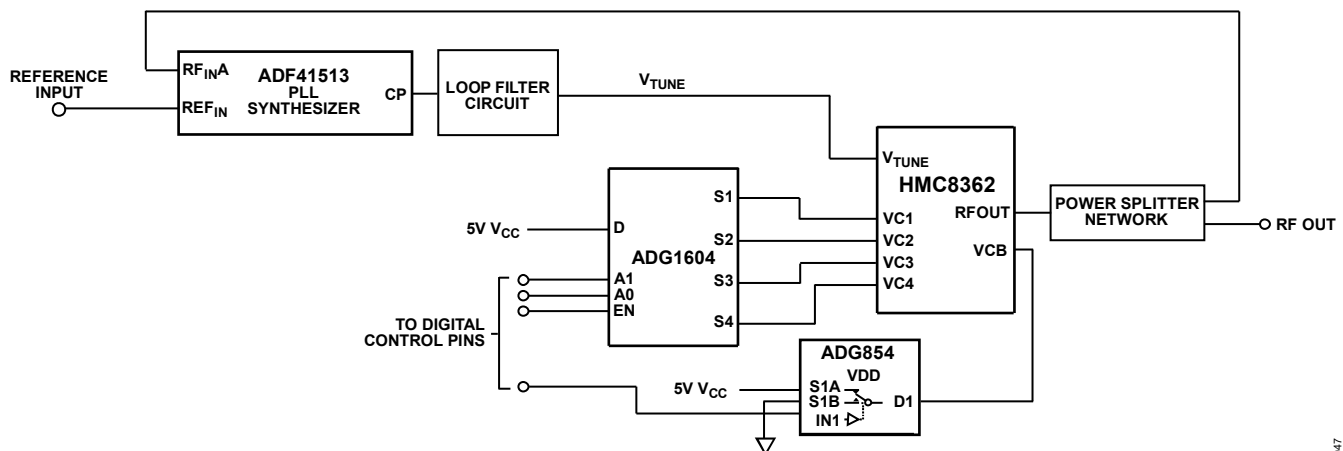
To achieve optimal performance of the VCO cores, including the lowest phase noise native to VCOs, high power supply rejection ratio (PSRR) and low dropout (LDO) regulators are recommended to minimize any spurious frequencies from the power supply, and to achieve the lowest phase noise native to the VCO. The [ADM7150](#) and the [LT3042](#) meet these requirements and are acceptable LDO regulators to use.

The wide frequency range of the VCO cores suggests the use of a low noise, PLL synthesizer, such as the [ADF41513](#). The wide input bandwidth of the ADF41513 (1 GHz to 26.5 GHz) makes it an ideal synthesizer to be used with the HMC8362. The charge pump current can be varied up or down on the ADF41513 to compensate for VCO sensitivity variation. Many applications require actively switching between the four VCO cores as quickly as possible. Enabling more than one VCO core at a time is not recommended. Therefore, use of an appropriate 4:1

multiplexer such as the [ADG1604](#) is recommended. The ADG1604 has low on resistance, the ability to operate with either 3 V or 5 V logic, and offers break before make switch sequencing. Alternatively, multiple [ADG854](#) switches can also be used to enable and disable the VCO cores. Although this switch also includes a break before make delay, users must prevent the possibility of powering up more than one VCO core at a time. Regardless of which approach is used to control the VCO cores, an additional ADG854 can be used to control bias to the upper portion of the cascode amplifier circuitry for use in muting the RF output (RFOUT, Pin 5) if desired. Muting RFOUT suppresses the output power by approximately 20 dB across all cores) and does not impact long-term reliability when only one VCO core is powered up at a time.

It is important to follow optimal RF layout practices for the layout of the interconnecting circuit. Give first priority to the layout of the interconnecting circuit. Give first priority to the microwave power splitter network from the output buffer of the VCO cores to the RF input pin (RF_{IN}A) of the ADF41513. Give the next highest priority to the highly sensitive V_{TUNE} line with the first pole placed as close to the ADF41513 CP output pin as possible, and the final RC pole of the filter placed as close to the HMC8362 V_{TUNE} pin as possible. The wide tuning range of the HMC8362 requires the use of a high voltage, low noise, operational amplifier. The [ADA4625-1](#) is acceptable to use for such applications.

The suggested PCB stackup consists of a high quality dielectric material, such as Rogers 4003. The transmission lines carrying the high frequency signal must be carefully controlled with 50 Ω characteristic impedances.



NOTES
1. THIS IS A SIMPLIFIED SCHEMATIC OF A TYPICAL APPLICATION DIAGRAM. PASSIVE COMPONENTS DETAILS HAVE BEEN OMITTED FOR CLARITY.

Figure 47. Typical Application Diagram

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OUTLINE DIMENSIONS

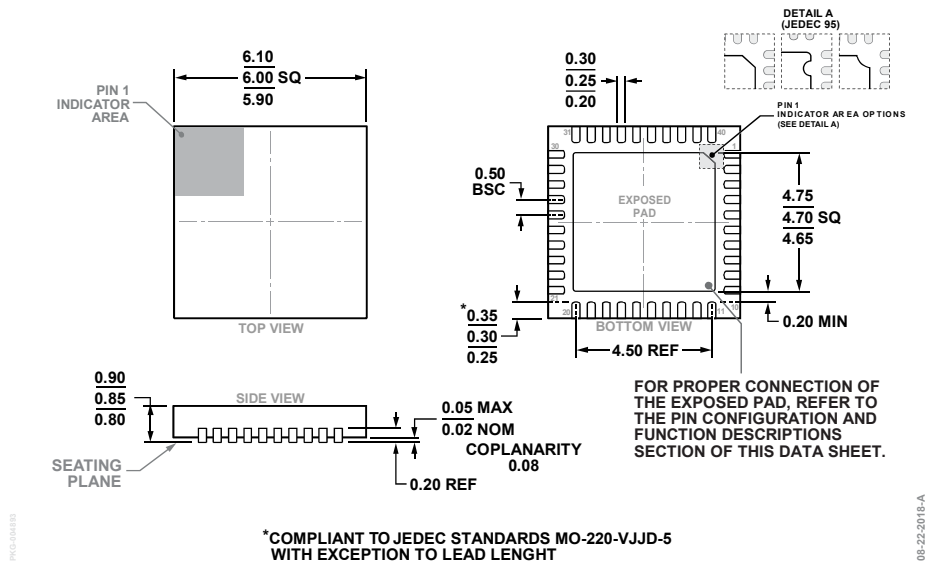


Figure 48. 40-Lead Lead Frame Chip Scale Package [LFCS]
6 mm × 6 mm Body and 0.85 mm Package Height
(HCP-40-1)

Dimensions shown in millimeters

ORDERING GUIDE

| Model ¹ | Temperature Range | MSL Rating ² | Package Description | Package Option | Ordering Quantity |
|--------------------|-------------------|-------------------------|--|----------------|-------------------|
| HMC8362LP6GE | -40°C to +85°C | MSL3 | 40-Lead Lead Frame Chip Scale Package [LFCS] | HCP-40-1 | 500 |
| HMC8362LP6GETR | -40°C to +85°C | MSL3 | 40-Lead Lead Frame Chip Scale Package [LFCS] | HCP-40-1 | |
| EV1HMC8362LP6G | | | Evaluation Board | | |

¹ All models are RoHS compliant.

² See the Absolute Maximum Ratings section.

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